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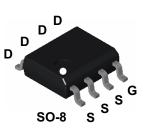
FDS6670AS 30V N-Channel PowerTrench[®] SyncFET[™]

General Description

The FDS6670AS is designed to replace a single SO-8 MOSFET and Schottky diode in synchronous DC:DC power supplies. This 30V MOSFET is designed to maximize power conversion efficiency, providing a low $R_{DS(ON)}$ and low gate charge. The FDS6670AS includes an integrated Schottky diode using Fairchild's monolithic SyncFET technology.

Applications

- DC/DC converter
- Low side notebook

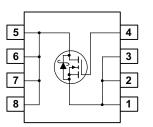


Features

• 13.5 A, 30 V. $R_{DS(ON)}$ max= 9.0 m Ω @ V_{GS} = 10 V $R_{DS(ON)}$ max= 11.5 m Ω @ V_{GS} = 4.5 V

July 2010

- Includes SyncFET Schottky body diode
- Low gate charge (27nC typical)
- High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$ and fast switching
- High power and current handling capability
- RoHS Compliant



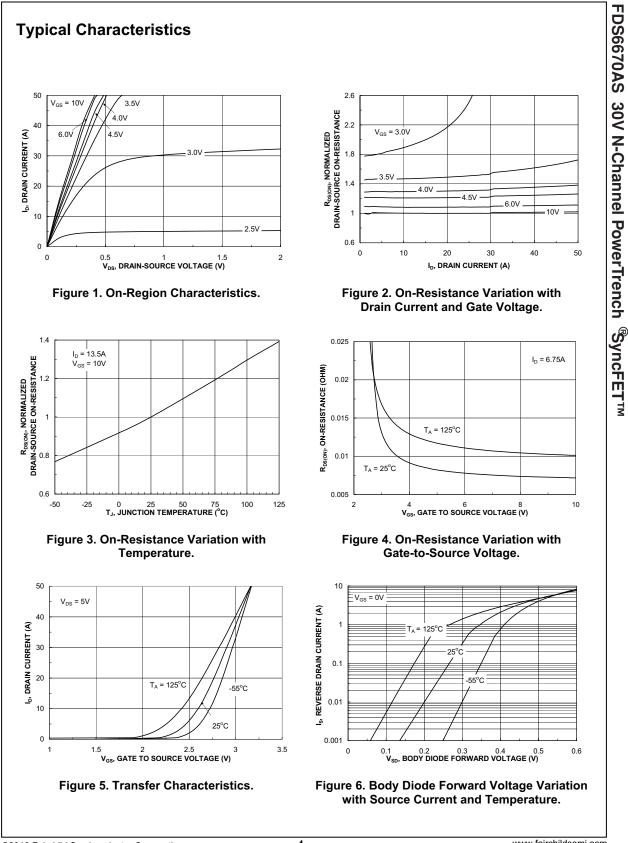
Symbol	Parameter		Ratings	Units		
V _{DSS}	Drain-So	urce Voltage		30	V	
V _{GSS}	Gate-Source Voltage		±20	V		
D	Drain Cu	rrent – Continuous	(Note 1a)	13.5	A	
	– Pulsed			50		
P _D	Power Dissipation for Single Operation (No		(Note 1a)	2.5	W	
			(Note 1b)	1.2		
			(Note 1c)	1		
T _J , T _{stg}	Operating and Storage Junction Temperature Range		-55 to +150	°C		
Therma _{Rөја} _{Rөјс}	Thermal	ICTERISTICS Resistance, Junction-to-Ambie Resistance, Junction-to-Case	ent (Note 1a) (Note 1)	50	°C/W	
		ing and Ordering In Device	formation Reel Size	Tape width	Quantity	
FDS6670AS		FDS6670AS	13"	12mm	2500 units	

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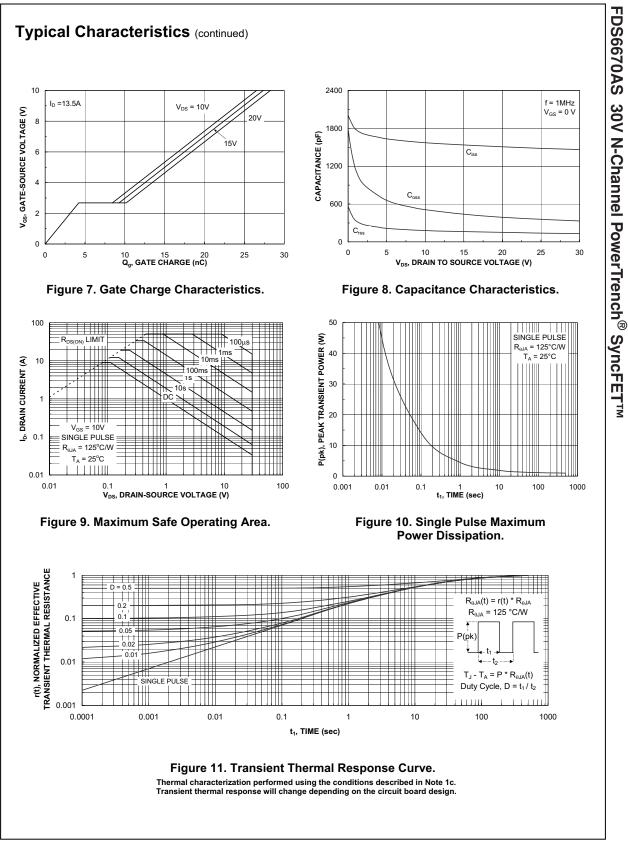
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V, I_{D} = 1 mA$	30			V
<u>ΔBVdss</u> ΔTj	Breakdown Voltage Temperature Coefficient $I_D = 10$ mA, Referenced to 25°C			27		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V$, $V_{GS} = 0 V$			500	μA
I _{GSS}	Gate–Body Leakage	$V_{\text{GS}} = \pm 20 \text{ V}, \qquad V_{\text{DS}} = 0 \text{ V}$			±100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 1 \text{ mA}$	1	1.7	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	I_D = 10 mA, Referenced to 25°C		-4		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance			7.5 9 10	9 11.5 12.5	mΩ
I _{D(on)}	On–State Drain Current	V_{GS} = 10 V, V_{DS} = 5 V	50			А
g _{FS}	Forward Transconductance	$V_{DS} = 10 V$, $I_{D} = 13.5 A$		66		S
Dynamic	Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 15 V, V _{GS} = 0 V,		1540		pF
Coss	Output Capacitance	f = 1.0 MHz		440		pF
C _{rss}	Reverse Transfer Capacitance			160		pF
R _g	Gate Resistance			2.1	4.2	Ω
Switchin	g Characteristics (Note 2)					
t _{d(on)}	Turn–On Delay Time			10	20	ns
t _r	Turn–On Rise Time	$V_{DS} = 15 V$, $I_D = 1 A$,		5	10	ns
t _d (_{off})	Turn–Off Delay Time	$V_{GS} = 10 \text{ V}, \qquad R_{GEN} = 6 \Omega$		27	44	ns
t _f	Turn–Off Fall Time			18	32	ns
t _{d(on)}	Turn–On Delay Time			13	23	ns
t _r	Turn–On Rise Time	$V_{DS} = 15 V$, $I_D = 1 A$,		15	27	ns
t _d (_{off})	Turn–Off Delay Time	V_{GS} = 4.5 V, R_{GEN} = 6 Ω		24	38	ns
t _f	Turn–Off Fall Time			13	23	ns
$\mathbf{Q}_{g(TOT)}$	Total Gate Charge at Vgs=10V			27	38	nC
Qg	Total Gate Charge at Vgs=5V	$V_{DD} = 15 V$, $I_D = 13.5 A$,		16	22	nC
Q_{gs}	Gate–Source Charge			4.2		nC
\mathbf{Q}_{gd}	Gate-Drain Charge			5.1		nC

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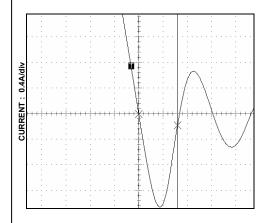
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Typical Characteristics (continued)

SyncFET Schottky Body Diode Characteristics

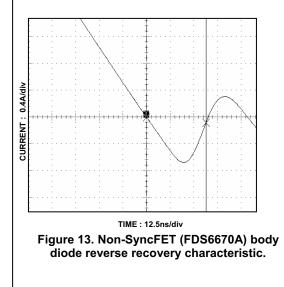
Fairchild's SyncFET process embeds a Schottky diode in parallel with PowerTrench MOSFET. This diode exhibits similar characteristics to a discrete external Schottky diode in parallel with a MOSFET. Figure 12 shows the reverse recovery characteristic of the FDS6670AS.



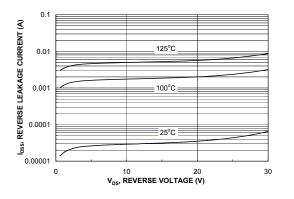
TIME : 12.5ns/div

Figure 12. FDS6670AS SyncFET body diode reverse recovery characteristic.

For comparison purposes, Figure 13 shows the reverse recovery characteristics of the body diode of an equivalent size MOSFET produced without SyncFET (FDS6670A).



Schottky barrier diodes exhibit significant leakage at high temperature and high reverse voltage. This will increase the power in the device.

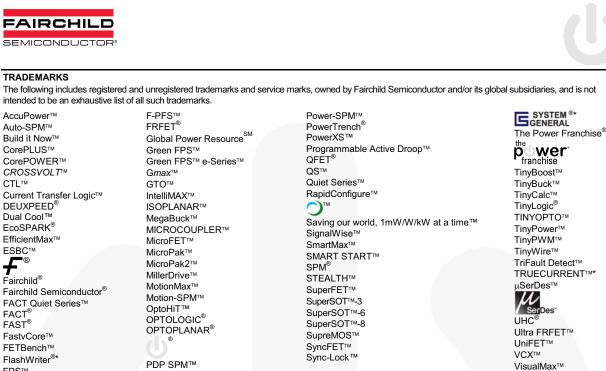


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Figure 14. SyncFET body diode reverse leakage versus drain-source voltage and temperature.



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